ENEE 303 Fall 2012 - Midterm Exam Continuation at Home Due start of class Th 11/08/12

Open book open notes; 50 points total (to add to midterm score). Good luck
For the following problems VDD $=10 \mathrm{~V}$.
All transistors have $\mathrm{KP}=4 \times 10^{-4}$, $|\mathrm{VTO}|=1$, LAMBDA $=0.01, \mathrm{~W} / \mathrm{L}=1 ; \mathrm{Cgs}=\mathrm{Cgd}=10 \mathrm{pFd}$ (with VTO $>0$ for NMOS, $<0$ for PMOS)

1. (25oints) For the following
a) Find the transistors' bias drain currents.
b) Draw the small signal equivalent circuit.
c) Give symbolically the transfer function $\mathrm{Vo} / \mathrm{Vi}(\mathrm{s})$.
d) Assume $\mathrm{C}=\mathrm{Cgd}$ and from c) find symbolically and numerically, when $\mathrm{L}=10 \mathrm{nHy}$, the poles and zeros of $\mathrm{Vo} / \mathrm{Vi}(\mathrm{s})$.

2. (25ints)

For the following circuit
a) Find VG and Vo for a source current of $I S=2 \mathrm{~mA}$ and then give gm and go.
b) Replace the VG battery so that only one battery, VDD, is used.
c) For the revised circuit of $b$ ) draw the small signal equivalent circuit including Cgs \& Cgd using generic symbols (= without numerical values).
d) Find the small signal input voltage to output drain current gain, $\mathrm{id} / \mathrm{vi}(\mathrm{s})$, and give its poles and zeros (all symbolically).


